



Ap 1765

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Vincent Derycke et al.
Serial No.: 09/856,211 Art Unit: 1765
Filing Date: May 18, 2001
Title: LARGE-SIZE MONOATOMIC AND MONOCRYSTALLINE
LAYER, MADE OF DIAMOND-TYPE CARBON AND
DEVICE FOR MAKING SAME
Docket No.: 33585

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

RECEIVED

Assistant Commissioner for Patents
Washington, D.C. 20231

FEB - 4 2002

TC 1700

Sir:

In accordance with Rule 56, applicants are aware of the patents and publications listed on Form PTO-1449. The pertinency of the teachings of these materials is discussed in the specification, and it is requested that they be considered by the examiner and be made of record in the examination of this application.

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Assistant Commissioner for Patents, Washington D.C. 20231 on the date indicated below.

Joseph J. Corso

Name of Attorney for Applicant(s)

11/1/2001

Date

Signature of Attorney

For the Examiner's convenience, it is noted that enclosed U.S. Patent No. 6,274,234 corresponds to FR 2 757 183 which was previously cited in the Information Disclosure Statement dated May 18, 2001. The French '183 patent discloses atomic wires of great length and great stability which are formed on the surface of a SiC substrate as straight chains of dimers of an element chosen from among SiC and C. In order to produce the same, layers of the element are formed on the surface and the assembly is constructed by means of annealings of the surface provided with the layers. The resulting wires have application to nanoelectronics.

If there are any fees resulting from this communication, please charge the same to Deposit Account No. 16-0820, Order No. 33585..

Respectfully submitted,

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November 1, 2001